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# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

MAX6018

## General Description

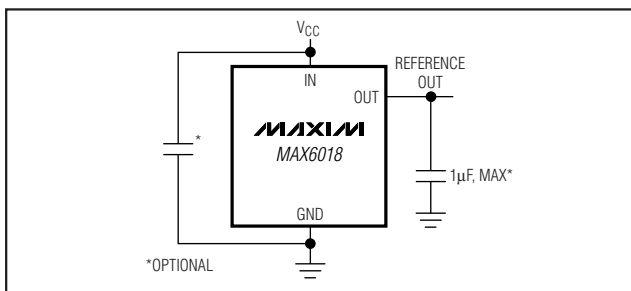
The MAX6018 is a precision, low-voltage, low-dropout, micropower voltage reference in a SOT23 package. This three-terminal reference operates with an input voltage from ( $V_{OUT} + 200mV$ ) to 5.5V, and is available with output voltage options of 1.2V, 1.6V, 1.8V, and 2.048V

The MAX6018 voltage reference consumes less than 5 $\mu A$  (max) of supply current and can source and sink up to 1mA of load current. Unlike conventional shunt-mode (two-terminal) references that waste supply current and require an external resistor, devices in the MAX6018 family offer a supply current that is virtually independent of supply voltage (with only 0.1 $\mu A/V$  variation with supply voltage) and do not require an external resistor. The MAX6018 has initial accuracies of 0.2% (A grade) and 0.4% (B grade) and temperature drift of 50ppm/ $^{\circ}C$  (max). The low-dropout voltage and the ultra-low, supply voltage-independent supply current make this device ideal for two-cell alkaline, end-of-life, battery-monitoring systems. The MAX6018 is available in a tiny 3-pin SOT23 package.

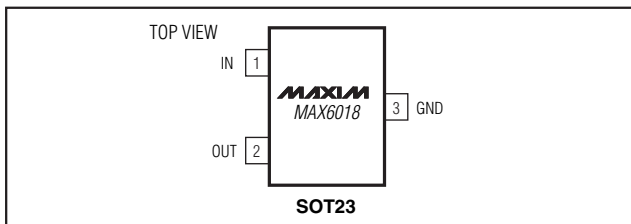
## Applications

Two-Cell, Battery-Operated Systems  
 Battery-Operated Equipment  
 Hand-Held Equipment  
 Data-Acquisition Systems  
 Industrial and Process-Control Systems

## Typical Application Circuit



## Pin Configuration



## Features

- ◆ Ultra-Low Supply Current: 5 $\mu A$  (max)
- ◆ 1.6V Output from 1.8V Input
- ◆ Ultra-Small, 3-Pin SOT23 Package
- ◆ Initial Accuracy:  $\pm 0.2\%$  (max)
- ◆ Low Temperature Drift: 50ppm/ $^{\circ}C$  (max)
- ◆ 200mV Dropout Voltage
- ◆ Load Regulation (1mA Source): 700 $\mu V/mA$  (max)
- ◆ Line Regulation ( $V_{OUT} + 200mV$ ) to 5.5V: 250 $\mu V/V$  (max)
- ◆ Four Output Voltage Options: 1.2V, 1.6V, 1.8V, 2.048V

## Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX6018AEUR12-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJH
MAX6018BEUR12-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJI
MAX6018AEUR16-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJJ
MAX6018BEUR16-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJK
MAX6018AEUR18-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJL
MAX6018BEUR18-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJM
MAX6018AEUR21-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJN
MAX6018BEUR21-T	-40 $^{\circ}C$ to +85 $^{\circ}C$	3 SOT23-3	FZJO

## Selector Guide

PART	OUTPUT VOLTAGE (V)	INITIAL ACCURACY (%)
MAX6018AEUR12	1.263	$\pm 0.2$
MAX6018BEUR12	1.263	$\pm 0.4$
MAX6018AEUR16	1.600	$\pm 0.2$
MAX6018BEUR16	1.600	$\pm 0.4$
MAX6018AEUR18	1.800	$\pm 0.2$
MAX6018BEUR18	1.800	$\pm 0.4$
MAX6018AEUR21	2.048	$\pm 0.2$
MAX6018BEUR21	2.048	$\pm 0.4$



# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

## ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to GND)

$V_{IN}$  .....-0.3V to +6V  
 Output Short-Circuit Duration to GND or  $V_{IN}$  .....Continuous  
 Continuous Power Dissipation ( $T_A = +70^\circ\text{C}$ )  
 3-Pin SOT23 (derate 4.0mW/ $^\circ\text{C}$  above +70 $^\circ\text{C}$ ).....320mW

Operating Temperature Range .....-40 $^\circ\text{C}$  to +85 $^\circ\text{C}$   
 Junction Temperature .....+150 $^\circ\text{C}$   
 Storage Temperature Range .....-65 $^\circ\text{C}$  to +150 $^\circ\text{C}$   
 Lead Temperature (soldering, 10s) .....+300 $^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS (MAX6018\_12–1.263V)

( $V_{IN} = 1.8\text{V}$ ;  $C_{OUT} = 47\text{nF}$ ,  $I_{OUT} = 0$ ;  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>OUTPUT</b>						
Output Voltage	$V_{OUT}$	MAX6018A_12 (0.2%)	1.2605	1.2630	1.2655	V
		MAX6018B_12 (0.4%)	1.2580	1.2630	1.2681	
Output Voltage Temperature Drift	$TCV_{OUT}$	(Note 2)		16	50	ppm/ $^\circ\text{C}$
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	$1.8\text{V} \leq V_{IN} \leq 5.5\text{V}$		50	400	$\mu\text{V}/\text{V}$
Load Regulation	$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	$0 \leq I_{OUT} \leq 1\text{mA}$		90	700	$\mu\text{V}/\text{mA}$
		$-100\mu\text{A} \leq I_{OUT} \leq 0$		2	9	$\mu\text{V}/\mu\text{A}$
Short-Circuit Current	$I_{SC}$	Sourcing to GND		3		mA
		Sinking from $V_{IN}$		6		
Long-Term Stability	$\frac{\Delta V_{OUT}}{\text{Time}}$	1000hrs at $T_A = +25^\circ\text{C}$		100		ppm
Thermal Hysteresis		(Note 4)		130		ppm
<b>DYNAMIC CHARACTERISTICS</b>						
Noise Voltage	$e_{OUT}$	0.1Hz to 10Hz		45		$\mu\text{Vp-p}$
		10Hz to 10kHz		100		$\mu\text{VRMS}$
Ripple Rejection		$V_{IN} = 1.8\text{V} \pm 100\text{mV}$ ( $f = 120\text{Hz}$ )		85		dB
Turn-On Settling Time	$t_R$	Settling to 0.1%; $C_{OUT} = 5\text{nF}$		200		$\mu\text{s}$
Capacitive-Load Stability Range	$C_{OUT}$	(Note 2)	47		1000	nF
<b>INPUT</b>						
Supply Voltage Range	$V_{IN}$	Guaranteed by Line Regulation Test	1.8		5.5	V
Quiescent Supply Current	$I_{IN}$	$T_A = +25^\circ\text{C}$		3	5	$\mu\text{A}$
		$T_A = T_{MIN}$ to $T_{MAX}$		3	6	
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$1.8\text{V} \leq V_{IN} \leq 5.5\text{V}$		0.1	0.5	$\mu\text{A}/\text{V}$

# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

**MAX6018**

## ELECTRICAL CHARACTERISTICS (MAX6018\_16–1.600V)

( $V_{IN} = 1.8V$ ;  $C_{OUT} = 47nF$ ,  $I_{OUT} = 0$ ;  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>OUTPUT</b>							
Output Voltage	$V_{OUT}$	MAX6018A_16 (0.2%)	$T_A = +25^\circ C$	1.5968	1.6000	1.6032	V
		MAX6018B_16 (0.4%)	$T_A = +25^\circ C$	1.5936	1.6000	1.6064	
Output Voltage Temperature Drift	$TCV_{OUT}$	(Note 2)		16	50	ppm/ $^\circ C$	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	$1.8V \leq V_{IN} \leq 5.5V$		40	250	$\mu V/V$	
Load Regulation	$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	$0 \leq I_{OUT} \leq 1mA$		90	700	$\mu V/mA$	
		$-750\mu A \leq I_{OUT} \leq 0$		0.6	50	$\mu V/\mu A$	
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	$I_{OUT} = 1mA$		100	200	mV	
Short-Circuit Current	$I_{SC}$	Sourcing to GND		6		mA	
		Sinking from $V_{IN}$		2			
Long-Term Stability	$\frac{\Delta V_{OUT}}{\text{Time}}$	1000hrs at $T_A = +25^\circ C$		100		ppm	
Thermal Hysteresis		(Note 4)		130		ppm	
<b>DYNAMIC CHARACTERISTICS</b>							
Noise Voltage	$e_{OUT}$	0.1Hz to 10Hz		40		$\mu V_{p-p}$	
		10Hz to 10kHz		150		$\mu V_{RMS}$	
Ripple Rejection		$V_{IN} = 1.8V \pm 100mV$ ( $f = 120Hz$ )		85		dB	
Turn-On Settling Time	$t_R$	Settling to 0.1%; $C_{OUT} = 5nF$		200		$\mu s$	
Capacitive-Load Stability Range	$C_{OUT}$	(Note 2)	0.1		1000	nF	
<b>INPUT</b>							
Supply Voltage Range	$V_{IN}$	Guaranteed by Line Regulation Test	1.8		5.5	V	
Quiescent Supply Current	$I_{IN}$	$T_A = +25^\circ C$		3	5	$\mu A$	
		$T_A = T_{MIN}$ to $T_{MAX}$		3	6		
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$1.8V \leq V_{IN} \leq 5.5V$		0.1	0.5	$\mu A/V$	

# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

## ELECTRICAL CHARACTERISTICS (MAX6018\_18–1.800V)

( $V_{IN} = 2.0V$ ;  $C_{OUT} = 47nF$ ,  $I_{OUT} = 0$ ;  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>OUTPUT</b>							
Output Voltage	$V_{OUT}$	MAX6018A_18 (0.2%)	$T_A = +25^\circ C$	1.7964	1.8000	1.8036	V
		MAX6018B_18 (0.4%)	$T_A = +25^\circ C$	1.7928	1.8000	1.8072	
Output Voltage Temperature Drift	$TCV_{OUT}$	(Note 2)		16	50	ppm/ $^\circ C$	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	$2.0V \leq V_{IN} \leq 5.5V$		40	275	$\mu V/V$	
Load Regulation	$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	$0 \leq I_{OUT} \leq 1mA$		90	800	$\mu V/mA$	
		$-1mA \leq I_{OUT} \leq 0$		0.4	50	$\mu V/\mu A$	
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	$I_{OUT} = 1mA$		100	200	mV	
Short-Circuit Current	$I_{SC}$	Sourcing to GND		7.5		mA	
		Sinking from $V_{IN}$		3			
Long-Term Stability	$\frac{\Delta V_{OUT}}{\text{Time}}$	1000hrs at $T_A = +25^\circ C$		100		ppm	
Thermal Hysteresis		(Note 4)		130		ppm	
<b>DYNAMIC CHARACTERISTICS</b>							
Noise Voltage	$e_{OUT}$	0.1Hz to 10Hz		45		$\mu V_{p-p}$	
		10Hz to 10kHz		160		$\mu V_{RMS}$	
Ripple Rejection		$V_{IN} = 2.0V \pm 100mV$ ( $f = 120Hz$ )		85		dB	
Turn-On Settling Time	$t_R$	Settling to 0.1%; $C_{OUT} = 5nF$		200		$\mu s$	
Capacitive-Load Stability Range	$C_{OUT}$	(Note 2)	0.1		1000	nF	
<b>INPUT</b>							
Supply Voltage Range	$V_{IN}$	Guaranteed by Line Regulation Test	2.0		5.5	V	
Quiescent Supply Current	$I_{IN}$	$T_A = +25^\circ C$		3	5	$\mu A$	
		$T_A = T_{MIN}$ to $T_{MAX}$		3	6		
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$2V \leq V_{IN} \leq 5.5V$		0.1	0.5	$\mu A/V$	

# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

MAX6018

## ELECTRICAL CHARACTERISTICS (MAX6018\_21–2.048V)

( $V_{IN} = 2.25V$ ;  $C_{OUT} = 47nF$ ,  $I_{OUT} = 0$ ;  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
<b>OUTPUT</b>							
Output Voltage	$V_{OUT}$	MAX6018A_21 (0.2%)	$T_A = +25^\circ C$	2.0439	2.0480	2.0521	V
		MAX6018B_21 (0.4%)	$T_A = +25^\circ C$	2.0398	2.0480	2.0562	
Output Voltage Temperature Drift	$TCV_{OUT}$	(Note 2)		16	50	ppm/ $^\circ C$	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN}}$	$2.25V \leq V_{IN} \leq 5.5V$		45	330	$\mu V/V$	
Load Regulation	$\frac{\Delta V_{OUT}}{\Delta I_{OUT}}$	$0 \leq I_{OUT} \leq 1mA$		90	1000	$\mu V/mA$	
		$-1mA \leq I_{OUT} \leq 0$		0.3	50	$\mu V/\mu A$	
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	$I_{OUT} = 1mA$		100	200	mV	
Short-Circuit Current	$I_{SC}$	Sourcing to GND		10		mA	
		Sinking from $V_{IN}$		4			
Long-Term Stability	$\frac{\Delta V_{OUT}}{\text{Time}}$	1000hrs at $T_A = +25^\circ C$		100		ppm	
Thermal Hysteresis		(Note 4)		130		ppm	
<b>DYNAMIC CHARACTERISTICS</b>							
Noise Voltage	$e_{OUT}$	0.1Hz to 10Hz		50		$\mu Vp-p$	
		10Hz to 10kHz		175		$\mu VRMS$	
Ripple Rejection		$V_{IN} = 2.25V \pm 100mV$ ( $f = 120Hz$ )		85		dB	
Turn-On Settling Time	$t_R$	Settling to 0.1%; $C_{OUT} = 5nF$		200		$\mu s$	
Capacitive-Load Stability Range	$C_{OUT}$	(Note 2)	0.1		1000	nF	
<b>INPUT</b>							
Supply Voltage Range	$V_{IN}$	Guaranteed by Line Regulation Test	2.25		5.5	V	
Quiescent Supply Current	$I_{IN}$	$T_A = +25^\circ C$		3	5	$\mu A$	
		$T_A = T_{MIN}$ to $T_{MAX}$		3	6		
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$2.25V \leq V_{IN} \leq 5.5V$		0.1	0.5	$\mu A/V$	

**Note 1:** Devices are 100% production tested at  $T_A = +25^\circ C$  and are guaranteed by design from  $T_A = T_{MIN}$  to  $T_{MAX}$ .

**Note 2:** Not production tested. Guaranteed by design.

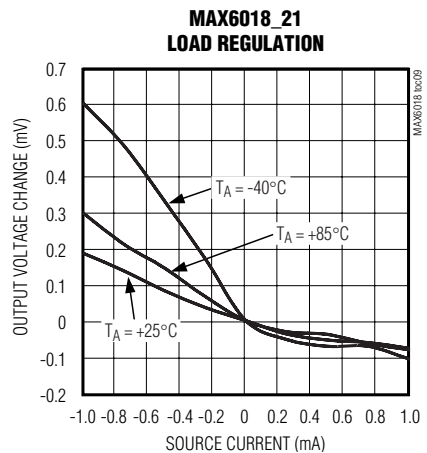
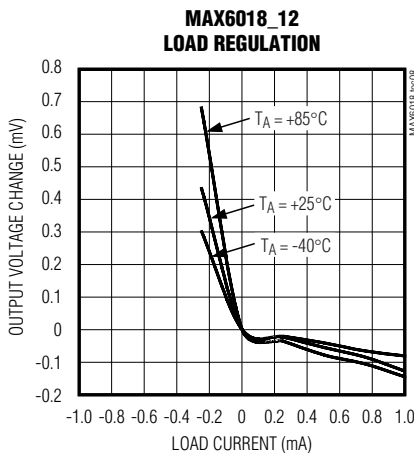
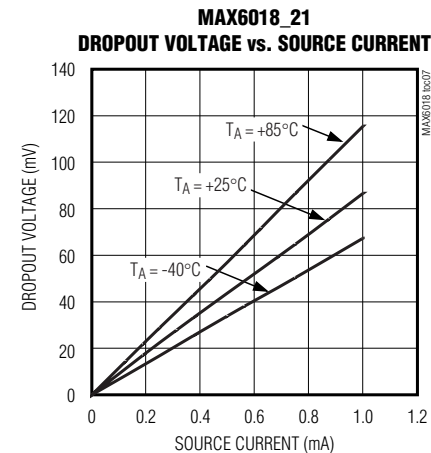
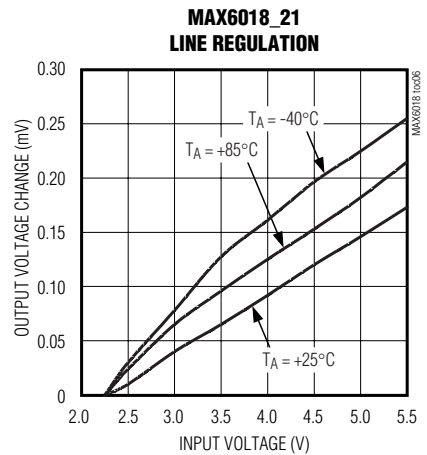
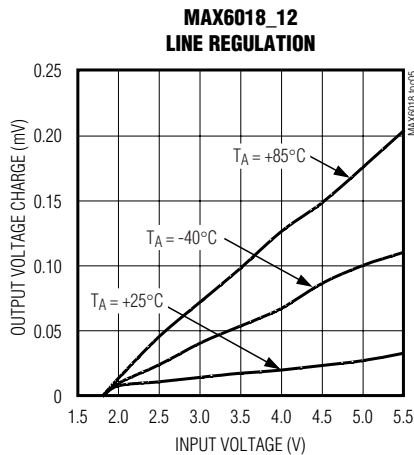
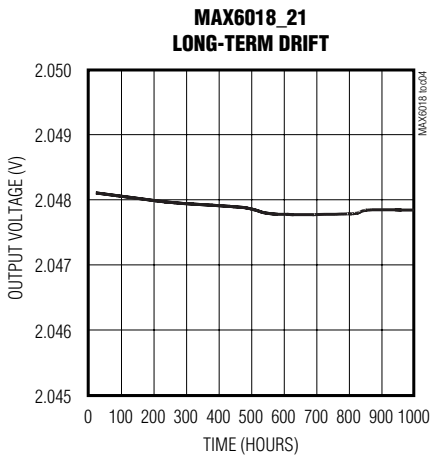
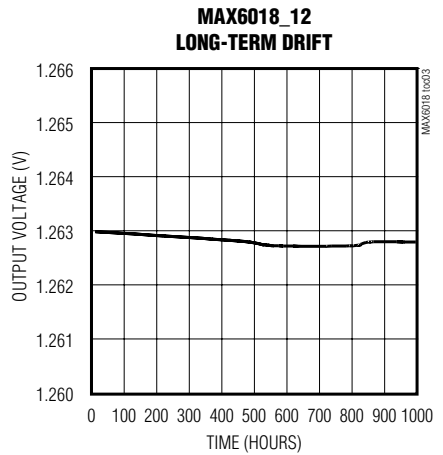
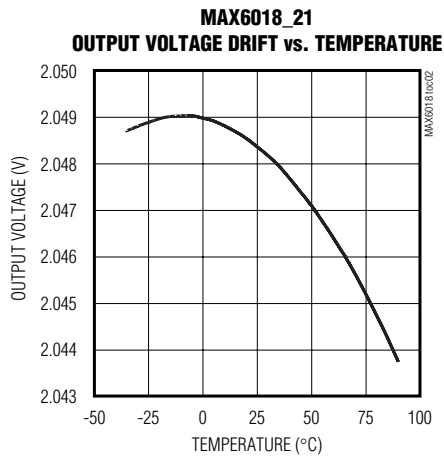
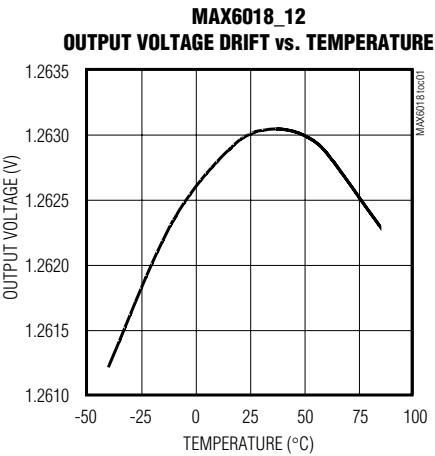
**Note 3:** Dropout voltage is the minimum input voltage at which  $V_{OUT}$  changes  $\leq 0.2\%$  from  $V_{OUT}$  at rated  $V_{IN}$  and is guaranteed by Load Regulation Test.

**Note 4:** Thermal hysteresis is defined as the change in  $T_A = +25^\circ C$  output voltage before and after temperature cycling of the device (from  $T_A = T_{MIN}$  to  $T_{MAX}$ ). Initial measurement at  $T_A = +25^\circ C$  is followed by temperature cycling the device to  $T_A = +85^\circ C$  then to  $T_A = -40^\circ C$  and another measurement at  $T_A = +25^\circ C$  is compared to the original measurement at  $T_A = +25^\circ C$ .

# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

## Typical Operating Characteristics

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

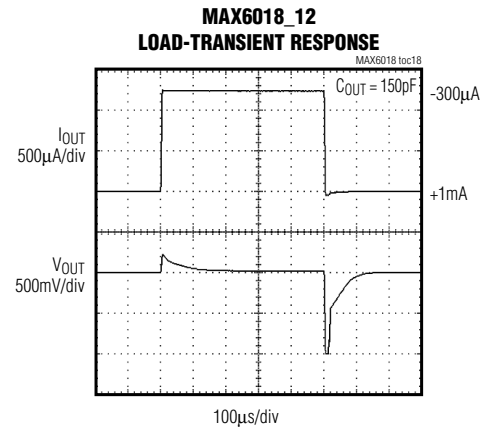
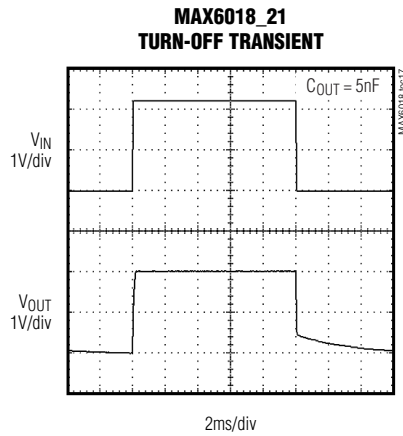
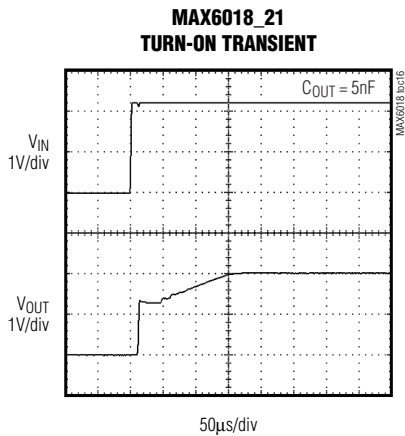
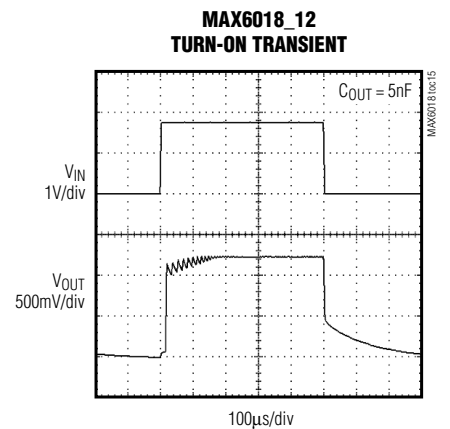
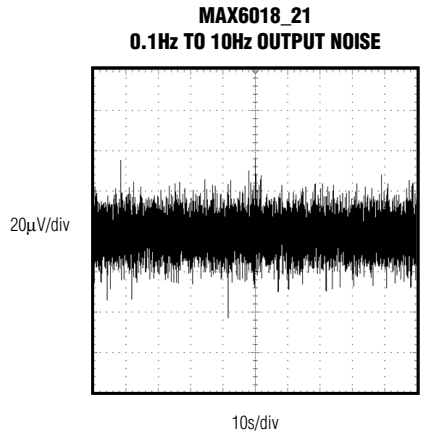
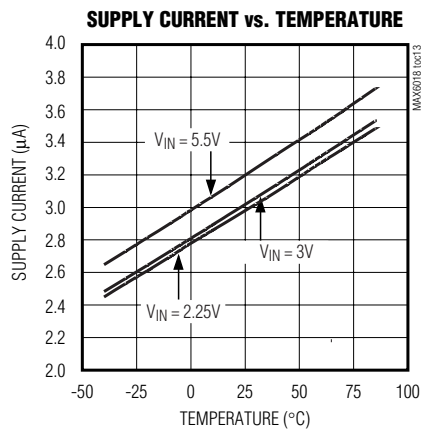
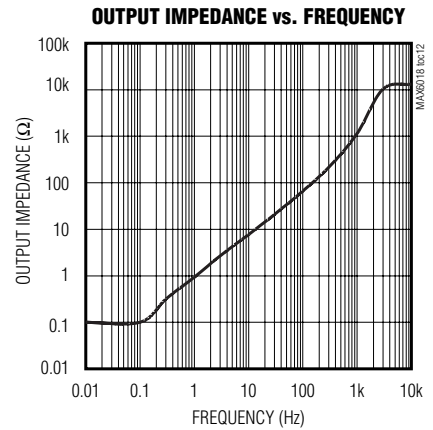
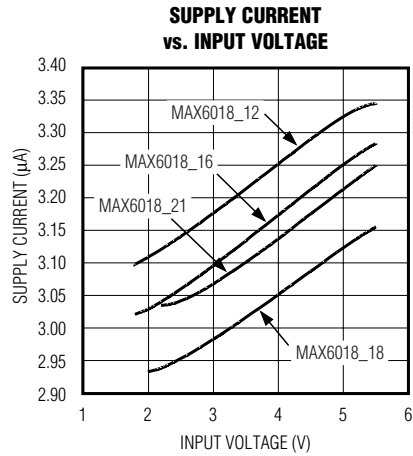
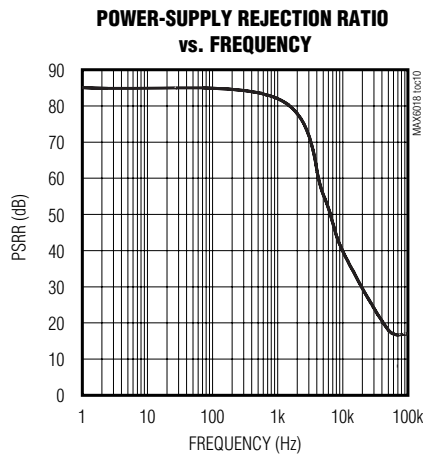


# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

## Typical Operating Characteristics (continued)

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

**MAX6018**

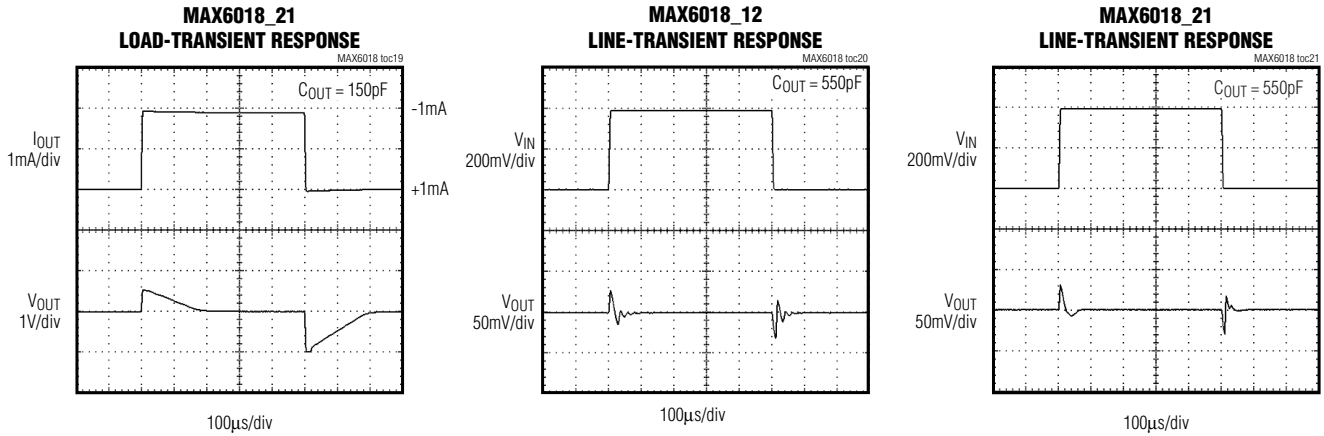




# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

## Typical Operating Characteristics (continued)

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)



### Detailed Description

The MAX6018 is a precision, low-voltage, low-dropout, micropower, bandgap voltage reference in a SOT23 package. This three-terminal reference operates with an input voltage from ( $V_{OUT} + 200\text{mV}$ ) to 5.5V, and is available with output voltage options of 1.2V, 1.6V, 1.8V, and 2.048V. These devices can source up to 1mA with  $<200\text{mV}$  of dropout voltage, making them attractive for use in low-voltage applications.

### Applications Information

#### Output/Load Capacitance

These devices require a minimum of 100pF load to maintain output stability.

They remain stable for capacitive loads as high as 1µF. In applications where the load or the supply can experience step changes, a larger output capacitor reduces the amount of overshoot (or undershoot) and assists the circuit's transient response. Otherwise, applications may not need more than 100pF.

#### Supply Current

The 5µA maximum supply current varies only 0.1µA/V with the supply voltage.

When the supply voltage is below the minimum-specified input voltage (as during turn-on), the devices can draw up to 20µA beyond the nominal supply current. The input voltage source must be capable of providing this current to ensure reliable turn-on.

### Pin Description

PIN	NAME	FUNCTION
1	IN	Supply Voltage Input. Bypass with a 0.1µF capacitor to ground.
2	OUT	Reference Voltage Output. Bypass with at least 100pF to ground. (See <i>Output/Load Capacitance</i> section).
3	GND	Ground

### Turn-On Time

These devices typically turn on and settle to within 0.1% of their final value in 200µs. The turn-on time can increase up to 1ms with the device operating at the minimum dropout voltage and the maximum load.

### Chip Information

TRANSISTOR COUNT: 87

PROCESS: BiCMOS

# Precision, Micropower, 1.8V Supply, Low-Dropout, SOT23 Voltage Reference

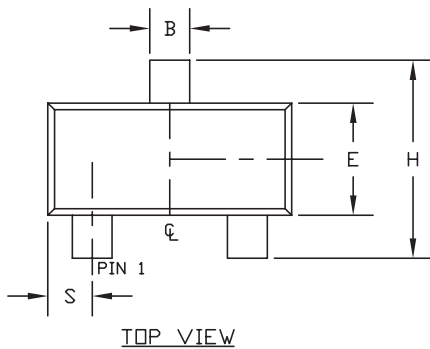
## Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)

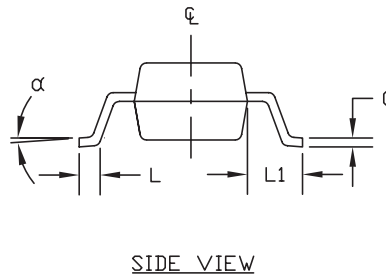
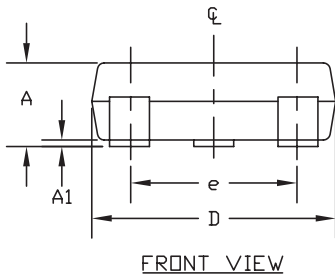
**MAX6018**

**NOTES:**

1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED .15mm (.006").
3. CONTROLLING DIMENSION: MILLIMETERS.
4. REFERENCE JEDEC TO236.
5. LEADS TO BE COPLANAR WITHIN 0.10mm.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.035	0.044	0.890	1.120
A1	0.001	0.004	0.013	0.100
B	0.015	0.020	0.370	0.510
C	0.003	0.071	0.085	0.180
D	0.110	0.120	2.800	3.040
E	0.047	0.055	1.200	1.400
e	0.070	0.081	1.780	2.050
H	0.083	0.104	2.100	2.640
L	0.008	0.017	0.210	0.420
L1	0.021	REF	0.54	REF
S	0.018	0.024	0.45	0.60
$\alpha$	0°	8°	0°	8°



<b>DALLAS SEMICONDUCTOR</b>			<b>MAXIM</b>		
PROPRIETARY INFORMATION					
TITLE: PACKAGE OUTLINE, 3L SOT-23					
APPROVAL	DOCUMENT CONTROL NO.	REV.			
	21-0051	E	1/1		

SOT23 LEFPS

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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